Schottky Diodes

Features

- For general purpose applications
- These diodes feature very low turn-on voltage and fast guard ring against excessive voltage, such as electrostatic discharges
- These diodes are also available in the SOD123 case with the type designations BAT42W-V to BAT43W-V and in MiniMELF SOD80 case with the type designations LL42 to LL43.
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Mechanical Data

Case: DO35 Glass Case
Weight: approx. 125 mg
Cathode Band Color: black
Packaging Codes/Options:
TR/10 k per 13" reel (52 mm tape), 50 k/box
TAP/10 k per Ammo tape (52 mm tape), 50 k/box

Parts Table

Part	Ordering code	Type Marking	Remarks
BAT42	BAT42-TR or BAT42-TAP	BAT42	Tape and Reel/Ammopack
BAT43	BAT43-TR or BAT43-TAP	BAT43	Tape and Reel/Ammopack

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V_{RRM}	30	V
Forward continuous current	T_{amb} = 25 °C	I_F	200[1)]	mA
Repetitive peak forward current	t_p < 1 s, δ < 0.5, T_{amb} = 25 °C	I_{FRM}	500[1)]	mA
Surge forward current	t_p < 10 ms, T_{amb} = 25 °C	I_{FSM}	4[1)]	A
Power dissipation[1)]	T_{amb} = 65 °C	P_{tot}	200[1)]	mW

[1)] Valid provided that leads at a distance of 4 mm from case are kept at ambient temperature

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air		R_{thJA}	300[1)]	K/W
Junction temperature		T_j	125	°C
Ambient operating temperature range		T_{amb}	- 65 to + 125	°C
Storage temperature range		T_{stg}	- 65 to +150	°C

[1)] Valid provided that leads at a distance of 4 mm from case are kept at ambient temperature

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Reverse breakdown voltage	I_R = 100 µA (pulsed)		$V_{(BR)}$	30			V
Leakage current[1)]	V_R = 25 V		I_R			0.5	µA
	V_R = 25 V, T_j = 100 °C		I_R			100	µA
Forward voltage[1)]	I_F = 200 mA		V_F			1000	mV
	I_F = 10 mA	BAT42	V_F			400	mV
	I_F = 50 mA	BAT42	V_F			650	mV
	I_F = 2 mA	BAT43	V_F	260		330	mV
	I_F = 15 mA	BAT43	V_F			450	mV
Diode capacitance	V_R = 1 V, f = 1 MHz		C_D		7		pF
Reverse recovery time	I_F = 10 mA, I_R = 10 mA, i_R = 1 mA, R_L = 100 Ω		t_{rr}			5	ns
Rectification efficieny	R_L = 15 kΩ, C_L = 300 pF, f = 45 MHz, V_{RF} = 2 V		η_v	80			%

[1)] Pulse test t_p < 300 µs, t_p/T < 0.02

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

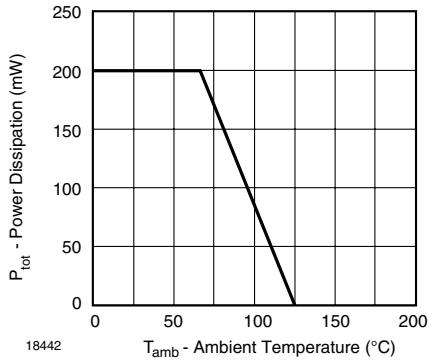

Figure 1. Admissible Power Dissipation vs. Ambient Temperature

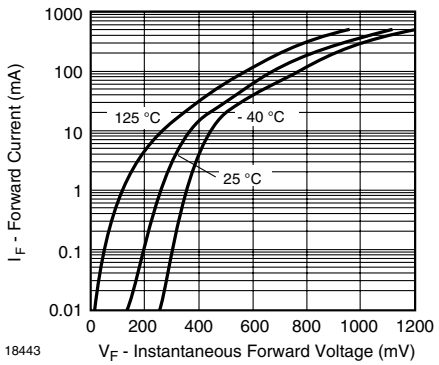

Figure 2. Typical Reverse Characteristics

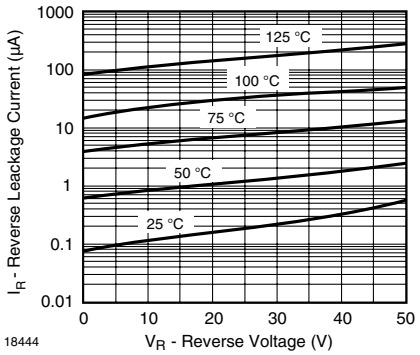

Figure 3. Typical Reverse Characteristics

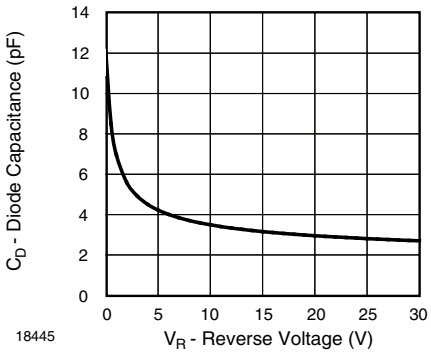

Figure 4. Typical Capacitance vs. Reverse Voltage

Package Dimensions in millimeters (inches): **DO35**